

# MPS2222, MPS2222A

MPS2222A is a Preferred Device

## General Purpose Transistors

NPN Silicon



ON Semiconductor™

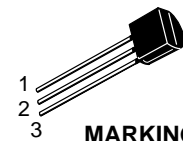
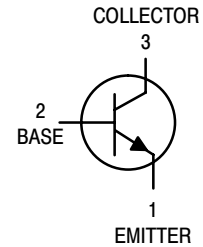
<http://onsemi.com>

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage MPS2222 MPS2222A	$V_{CEO}$	30 40	Vdc
Collector–Base Voltage MPS2222 MPS2222A	$V_{CBO}$	60 75	Vdc
Emitter–Base Voltage MPS2222 MPS2222A	$V_{EBO}$	5.0 6.0	Vdc
Collector Current – Continuous	$I_C$	600	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.5 12	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

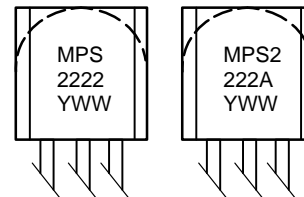
### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$



TO-92  
CASE 29  
STYLE 1

### MARKING DIAGRAMS



Y = Year  
WW = Work Week

### ORDERING INFORMATION

Device	Package	Shipping
MPS2222	TO-92	5000 Units/Box
MPS2222A	TO-92	5000 Units/Box
MPS2222ARLRA	TO-92	2000/Tape & Reel
MPS2222ARLRM	TO-92	2000/Ammo Pack
MPS2222ARLRP	TO-92	2000/Ammo Pack
MPS2222RLRA	TO-92	2000/Tape & Reel
MPS2222RLRM	TO-92	2000/Ammo Pack
MPS2222RLRP	TO-92	2000/Ammo Pack

Preferred devices are recommended choices for future use and best overall value.

# MPS2222, MPS2222A

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA <sub>dc</sub> , I <sub>B</sub> = 0)	MPS2222 MPS2222A	V <sub>(BR)CEO</sub>	30 40	– –	V <sub>dc</sub>
Collector–Base Breakdown Voltage (I <sub>C</sub> = 10 μA <sub>dc</sub> , I <sub>E</sub> = 0)	MPS2222 MPS2222A	V <sub>(BR)CBO</sub>	60 75	– –	V <sub>dc</sub>
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 10 μA <sub>dc</sub> , I <sub>C</sub> = 0)	MPS2222 MPS2222A	V <sub>(BR)EBO</sub>	5.0 6.0	– –	V <sub>dc</sub>
Collector Cutoff Current (V <sub>CE</sub> = 60 V <sub>dc</sub> , V <sub>EB(off)</sub> = 3.0 V <sub>dc</sub> )	MPS2222A	I <sub>CEX</sub>	–	10	nA <sub>dc</sub>
Collector Cutoff Current (V <sub>CB</sub> = 50 V <sub>dc</sub> , I <sub>E</sub> = 0) (V <sub>CB</sub> = 60 V <sub>dc</sub> , I <sub>E</sub> = 0) (V <sub>CB</sub> = 50 V <sub>dc</sub> , I <sub>E</sub> = 0, T <sub>A</sub> = 125°C) (V <sub>CB</sub> = 50 V <sub>dc</sub> , I <sub>E</sub> = 0, T <sub>A</sub> = 125°C)	MPS2222 MPS2222A MPS2222 MPS2222A	I <sub>CBO</sub>	– – – –	0.01 0.01 10 10	μA <sub>dc</sub>
Emitter Cutoff Current (V <sub>EB</sub> = 3.0 V <sub>dc</sub> , I <sub>C</sub> = 0)	MPS2222A	I <sub>EBO</sub>	–	100	nA <sub>dc</sub>
Base Cutoff Current (V <sub>CE</sub> = 60 V <sub>dc</sub> , V <sub>EB(off)</sub> = 3.0 V <sub>dc</sub> )	MPS2222A	I <sub>BL</sub>	–	20	nA <sub>dc</sub>
<b>ON CHARACTERISTICS</b>					
DC Current Gain (I <sub>C</sub> = 0.1 mA <sub>dc</sub> , V <sub>CE</sub> = 10 V <sub>dc</sub> ) (I <sub>C</sub> = 1.0 mA <sub>dc</sub> , V <sub>CE</sub> = 10 V <sub>dc</sub> ) (I <sub>C</sub> = 10 mA <sub>dc</sub> , V <sub>CE</sub> = 10 V <sub>dc</sub> ) (I <sub>C</sub> = 10 mA <sub>dc</sub> , V <sub>CE</sub> = 10 V <sub>dc</sub> , T <sub>A</sub> = –55°C) (I <sub>C</sub> = 150 mA <sub>dc</sub> , V <sub>CE</sub> = 10 V <sub>dc</sub> ) (Note 1.) (I <sub>C</sub> = 150 mA <sub>dc</sub> , V <sub>CE</sub> = 1.0 V <sub>dc</sub> ) (Note 1.) (I <sub>C</sub> = 500 mA <sub>dc</sub> , V <sub>CE</sub> = 10 V <sub>dc</sub> ) (Note 1.)	MPS2222A only     MPS2222 MPS2222A	h <sub>FE</sub>	35 50 75 35 100 50 30 40	– – – – 300 – – –	–
Collector–Emitter Saturation Voltage (Note 1.) (I <sub>C</sub> = 150 mA <sub>dc</sub> , I <sub>B</sub> = 15 mA <sub>dc</sub> )  (I <sub>C</sub> = 500 mA <sub>dc</sub> , I <sub>B</sub> = 50 mA <sub>dc</sub> )	MPS2222 MPS2222A  MPS2222 MPS2222A	V <sub>CE(sat)</sub>	– – – –	0.4 0.3 1.6 1.0	V <sub>dc</sub>
Base–Emitter Saturation Voltage (Note 1.) (I <sub>C</sub> = 150 mA <sub>dc</sub> , I <sub>B</sub> = 15 mA <sub>dc</sub> )  (I <sub>C</sub> = 500 mA <sub>dc</sub> , I <sub>B</sub> = 50 mA <sub>dc</sub> )	MPS2222 MPS2222A  MPS2222 MPS2222A	V <sub>BE(sat)</sub>	– 0.6 – –	1.3 1.2 2.6 2.0	V <sub>dc</sub>

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

# MPS2222, MPS2222A

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
<b>SMALL-SIGNAL CHARACTERISTICS</b>				
Current-Gain – Bandwidth Product (Note 2.) ( $I_C = 20\text{ mA}$ , $V_{CE} = 20\text{ V}$ , $f = 100\text{ MHz}$ )	$f_T$	250 300	– –	MHz
Output Capacitance ( $V_{CB} = 10\text{ V}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )	$C_{obo}$	–	8.0	pF
Input Capacitance ( $V_{EB} = 0.5\text{ V}$ , $I_C = 0$ , $f = 1.0\text{ MHz}$ )	$C_{ibo}$	– –	30 25	pF
Input Impedance ( $I_C = 1.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ )	$h_{ie}$	2.0 0.25	8.0 1.25	k $\Omega$
Voltage Feedback Ratio ( $I_C = 1.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ )	$h_{re}$	– –	8.0 4.0	$\times 10^{-4}$
Small-Signal Current Gain ( $I_C = 1.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ )	$h_{fe}$	50 75	300 375	–
Output Admittance ( $I_C = 1.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ ) ( $I_C = 10\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ )	$h_{oe}$	5.0 25	35 200	$\mu\text{mhos}$
Collector Base Time Constant ( $I_E = 20\text{ mA}$ , $V_{CB} = 20\text{ V}$ , $f = 31.8\text{ MHz}$ )	$r_b' C_C$	–	150	ps
Noise Figure ( $I_C = 100\text{ }\mu\text{A}$ , $V_{CE} = 10\text{ V}$ , $R_S = 1.0\text{ k}\Omega$ , $f = 1.0\text{ kHz}$ )	NF	–	4.0	dB

## SWITCHING CHARACTERISTICS MPS2222A only

Delay Time	$(V_{CC} = 30\text{ V}$ , $V_{BE(\text{off})} = -0.5\text{ V}$ , $I_C = 150\text{ mA}$ , $I_{B1} = 15\text{ mA}$ ) (Figure 1)	$t_d$	–	10	ns
Rise Time		$t_r$	–	25	ns
Storage Time	$(V_{CC} = 30\text{ V}$ , $I_C = 150\text{ mA}$ , $I_{B1} = I_{B2} = 15\text{ mA}$ ) (Figure 2)	$t_s$	–	225	ns
Fall Time		$t_f$	–	60	ns

2.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

## SWITCHING TIME EQUIVALENT TEST CIRCUITS

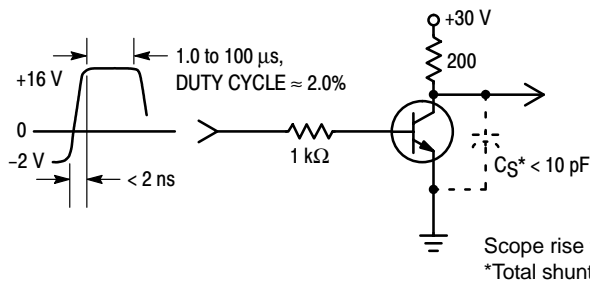


Figure 1. Turn-On Time

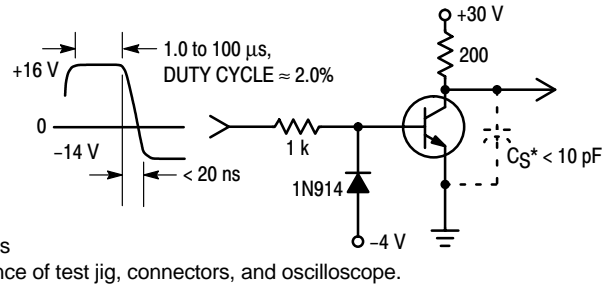


Figure 2. Turn-Off Time

# MPS2222, MPS2222A

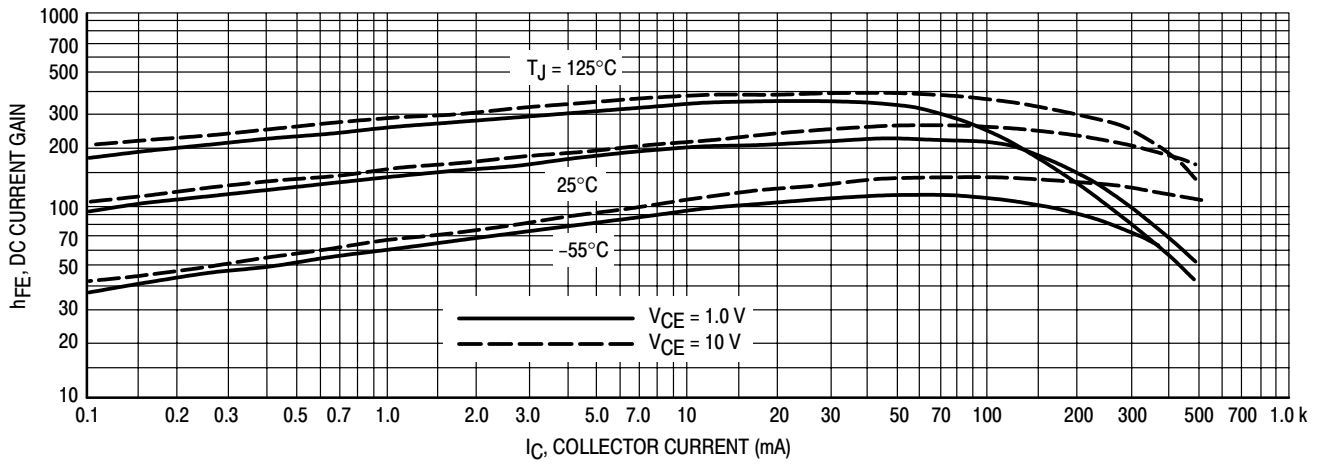


Figure 3. DC Current Gain

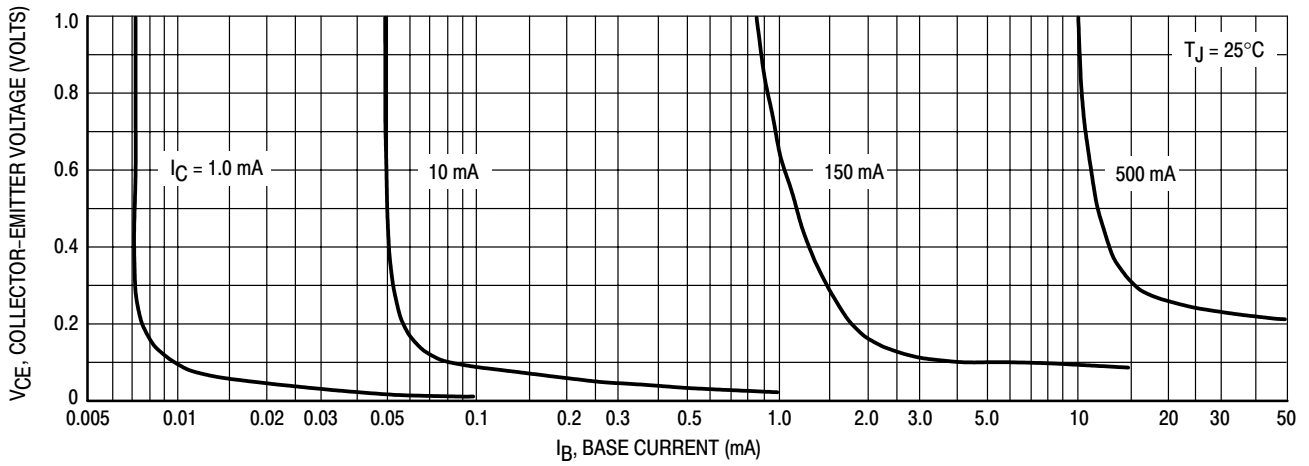


Figure 4. Collector Saturation Region

# MPS2222, MPS2222A

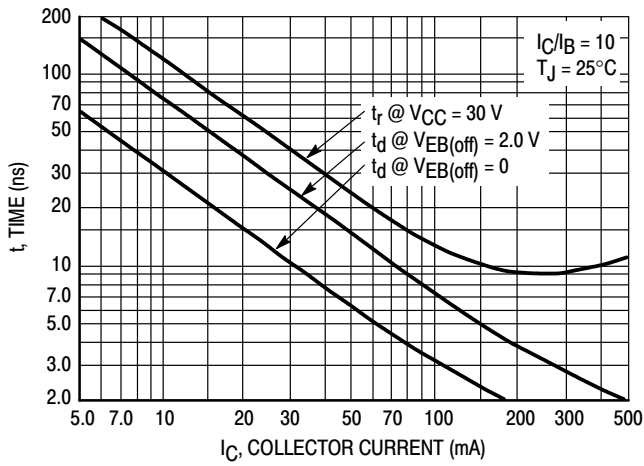


Figure 5. Turn-On Time

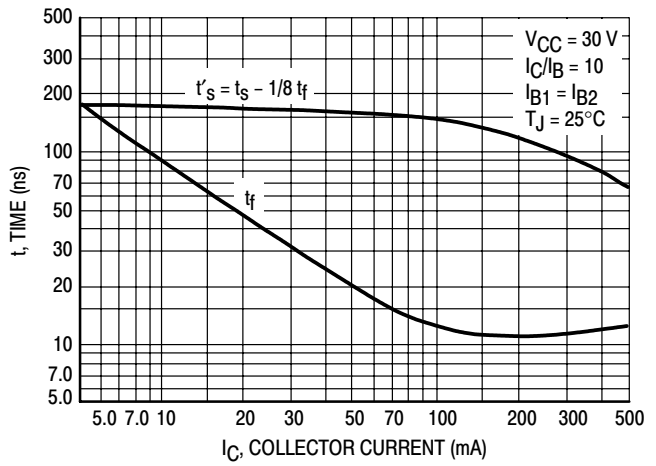


Figure 6. Turn-Off Time

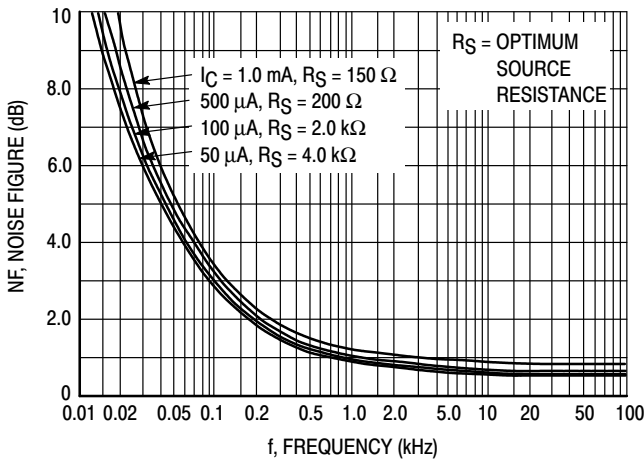


Figure 7. Frequency Effects

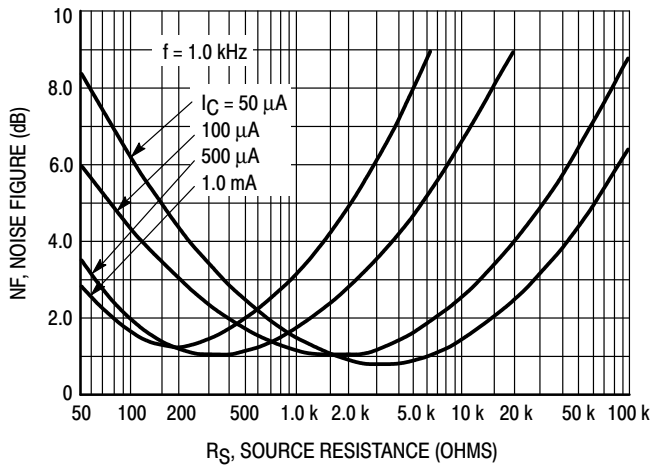


Figure 8. Source Resistance Effects

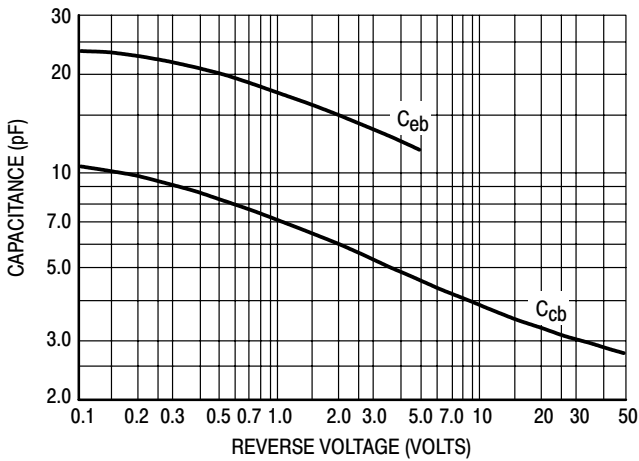


Figure 9. Capacitances

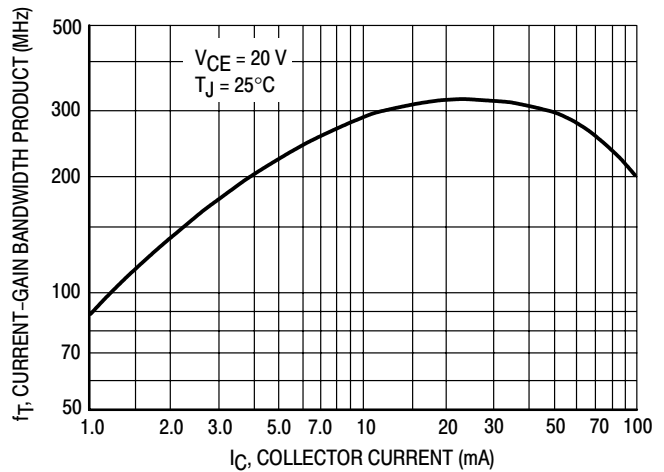


Figure 10. Current-Gain Bandwidth Product

# MPS2222, MPS2222A

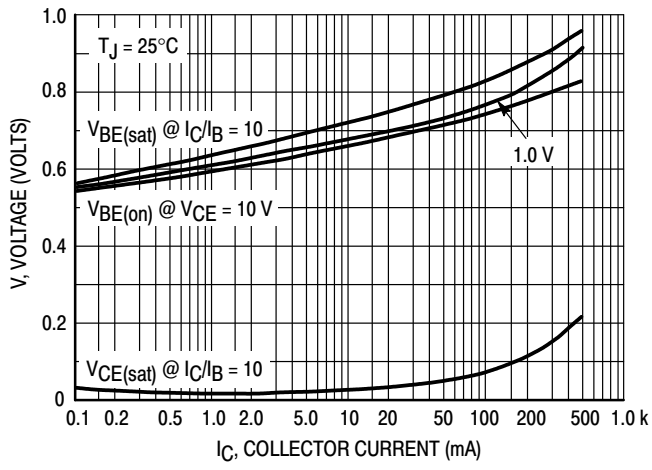


Figure 11. "On" Voltages

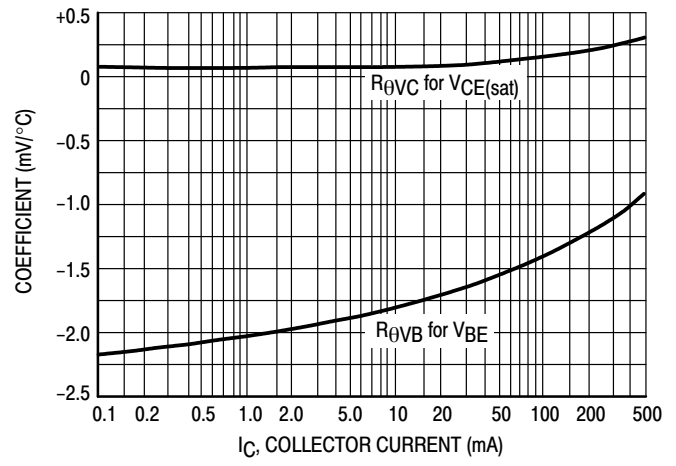
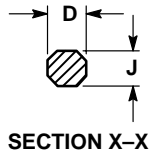
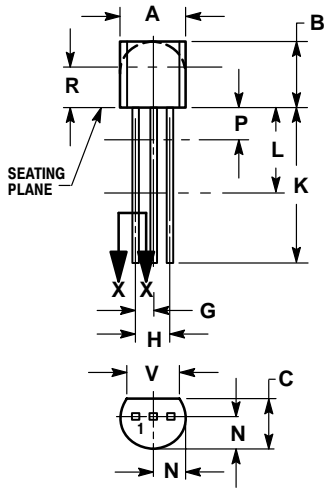


Figure 12. Temperature Coefficients

# MPS2222, MPS2222A

## PACKAGE DIMENSIONS

TO-92  
TO-226AA  
CASE 29-11  
ISSUE AL



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---


### STYLE 1:

- PIN 1. EMITTER
- BASE
- COLLECTOR

### STYLE 14:

- PIN 1. EMITTER
- COLLECTOR
- BASE

# MPS2222, MPS2222A

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